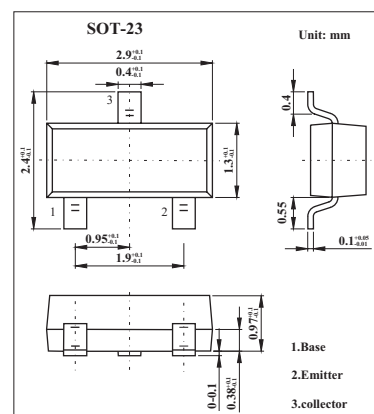


High-voltage Amplifier Transistor

2SC3906K

■ Features

- High breakdown voltage.

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|-----------------------------|-----------|-------------|------------------|
| Collector-base voltage | V_{CB0} | 120 | V |
| Collector-emitter voltage | V_{CE0} | 120 | V |
| Emitter-base voltage | V_{EB0} | 5 | V |
| Collector current | I_c | 50 | mA |
| Collector power dissipation | P_c | 0.2 | W |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Testconditons | Min | Typ | Max | Unit |
|--------------------------------------|---------------|---|-----|-----|-----|---------------|
| Collector-base breakdown voltage | BV_{CB0} | $I_c=50\mu\text{A}$ | 120 | | | V |
| Collector-emitter breakdown voltage | BV_{CE0} | $I_c=1\text{mA}$ | 120 | | | V |
| Emitter-base breakdown voltage | BV_{EB0} | $I_E=50\mu\text{A}$ | 5 | | | V |
| Collector cutoff current | I_{cBO} | $V_{CB}=100\text{V}$ | | | 0.5 | μA |
| Emitter cutoff current | I_{EBO} | $V_{EB}=4\text{V}$ | | | 0.5 | μA |
| DC current transfer ratio | h_{FE} | $V_{CE}=6\text{V}, I_c=2\text{mA}$ | 180 | | 560 | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_c=10\text{mA}, I_B=1\text{mA}$ | | | 0.5 | V |
| Output capacitance | f_T | $V_{CE}=-12\text{V}, I_E=2\text{mA}, f=100\text{MHz}$ | | 140 | | MHz |
| Transition frequency | C_{ob} | $V_{CB}=-12\text{V}, I_E=0\text{A}, f=1\text{MHz}$ | | 2.5 | | pF |

■ h_{FE} Classification

| Marking | TR | TS |
|----------|---------|---------|
| Rank | R | S |
| h_{FE} | 180~390 | 270~560 |